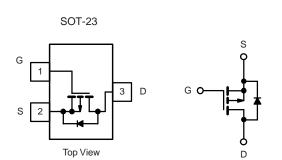
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P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}$ (Ω) Max.	I _D (A) ^a	Q _g (Typ.)		
- 20	0.0320 at V _{GS} = - 4.5 V	- 5.9			
	0.0410 at V _{GS} = - 2.5 V	- 5.2	13.8 nC		
	0.0675 at V _{GS} = - 1.8 V	- 4.3			



FEATURES

- DT-Trench Power MOSFET
- 100 % R_g Tested
- Built-in ESD Protection
 - Typical ESD Performance 3000 V



ROHS

APPLICATIONS

- Power Management for Portable and Consumer
 - Load Switches
 - DC/DC Converters

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	- 20	V
Gate-Source Voltage		V _{GS}	± 8	¬
	T _C = 25 °C		- 5.9	
Continuous Prain Current (T = 150 °C)	T _C = 70 °C	1_	- 4.7	
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	- 4.5 ^{b, c}	
	T _A = 70 °C		- 3.6 ^{b, c}	A
Pulsed Drain Current (t = 300 μs)		I _{DM}	- 20	
Continuous Source-Drain Diode Current	T _C = 25 °C	lo	- 1.4	
Continuous Source-Diam Diode Current	T _A = 25 °C	ls –	- 1 ^{b, c}	
	T _C = 25 °C		1.7	
Maximum Power Dissipation	T _C = 70 °C	P _D	1.1	w
Maximum Fower Dissipation	T _A = 25 °C	' D	1 ^{b, c}	
	T _A = 70 °C		0.6 ^{b, c}	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C
Soldering Recommendations (Peak Temperature) ^{d, e}			260	7 ~

P-Channel MOSFET

THERMAL RESISTANCE RATII	NGS				
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R_{thJA}	100	130	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	60	75	O/ VV

Notes:

- a. $T_C = 25$ °C.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. Maximum under steady state conditions is 175 °C/W.



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	•			•			
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 20			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = - 250 μA		- 14		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	η - 230 μΑ -		2.5		IIIV/ C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	- 0.4		- 1	٧	
Gate-Source Leakage	looo	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 10		
Gale-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1		
Zero Gate Voltage Drain Current	1	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			- 10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 15			Α	
Drain-Source On-State Resistance ^a		V _{GS} = - 4.5 V, I _D = - 4 A		0.0265	0.0320		
	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 4 A		0.0340	0.0410	Ω	
		V _{GS} = - 1.8 V, I _D = - 2 A		0.0465	0.0675		
Dynamic ^b	•						
Total Gate Charge	Qg	V _{DS} = - 10 V, V _{GS} = - 8 V, I _D = - 4.5 A		23.8	36	nC	
				13.8	21		
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -4.5 \text{ A}$		1.9			
Gate-Drain Charge	Q_{gd}			3			
Gate Resistance	R_{g}	f = 1 MHz	2.2	11	22	Ω	
Turn-On Delay Time	t _{d(on)}			22	33		
Rise Time	t _r	$V_{DD} = -10 \text{ V}, R_{L} = 2.8 \Omega$		21	32		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -3.6 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		62	93		
Fall Time	t _f			14	21	ns	
Turn-On Delay Time	t _{d(on)}			9	18	113	
Rise Time	t _r	$V_{DD} = -10 \text{ V}, R_{L} = 2.8 \Omega$		6	12		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -3.6 \text{ A}, V_{GEN} = -8 \text{ V}, R_g = 1 \Omega$		65	98		
Fall Time	t _f			15	23		
Drain-Source Body Diode Characterist	ics			_			
Continuous Source-Drain Diode Current	I _S	$T_C = 25 ^{\circ}C$			- 1.4	Α	
Pulse Diode Forward Current	I _{SM}				- 20		
Body Diode Voltage	V_{SD}	I _S = - 3.6 A, V _{GS} = 0 V		- 0.8	- 1.2	٧	
Body Diode Reverse Recovery Time	t _{rr}			13	20	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	 I _E = - 3.6 A, dl/dt = 100 A/μs, T _{.I} = 25 °C		5	10	nC	
Reverse Recovery Fall Time	t _a	$\frac{1}{1}$ $\frac{1}$		8			
Reverse Recovery Rise Time	t _b	j		5		ns	

Notes:

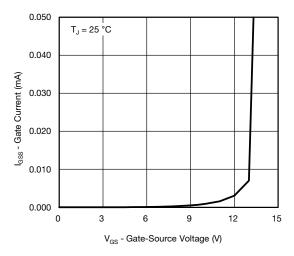
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

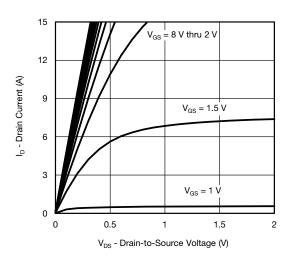
b. Guaranteed by design, not subject to production testing.



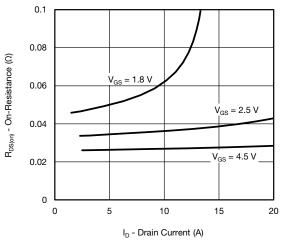
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



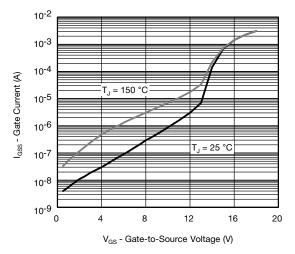
Gate Current vs. Gate-Source Voltage



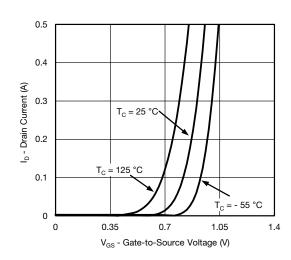
Output Characteristics



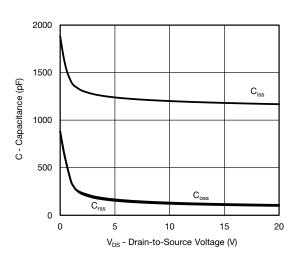
On-Resistance vs. Drain Current



Gate Current vs. Gate-Source Voltage



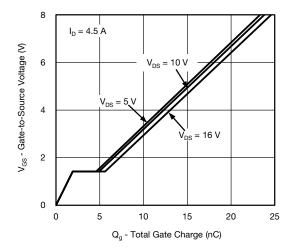
Transfer Characteristics



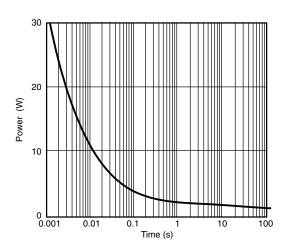
Capacitance



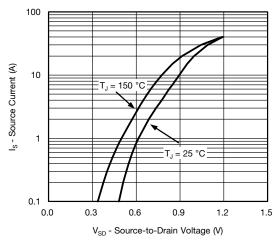
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



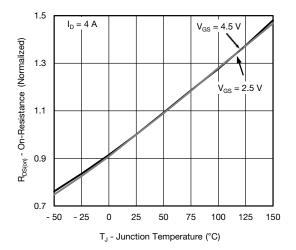
Gate Charge



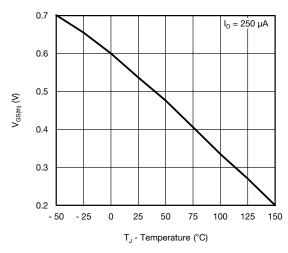
Single Pulse Power, Junction-to-Ambient



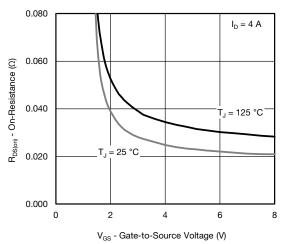
Soure-Drain Diode Forward Voltage



On-Resistance vs. Junction Temperature



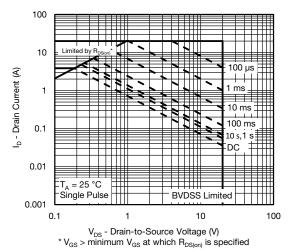
Threshold Voltage



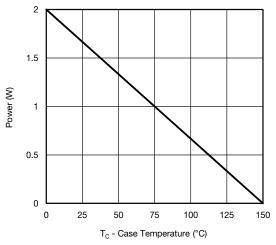
On-Resistance vs. Gate-to-Source Voltage



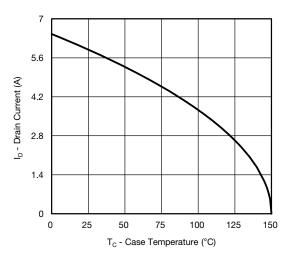
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



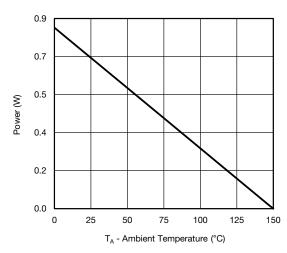
Safe Operating Area, Junction-to-Ambient



Power Junction-to-Case



Current Derating*

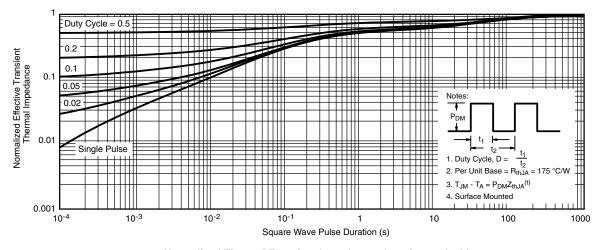


Power Junction-to-Ambient

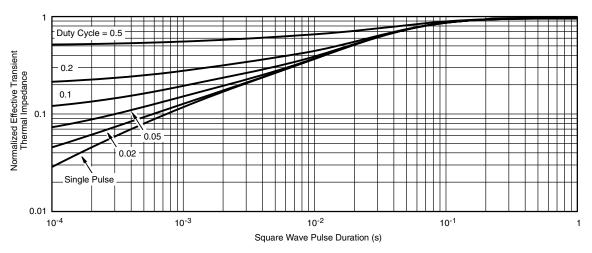
^{*} The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



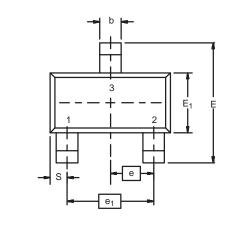
Normalized Thermal Transient Impedance, Junction-to-Ambient

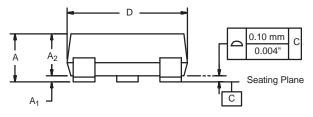


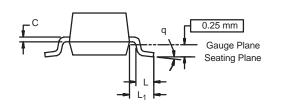
Normalized Thermal Transient Impedance, Junction-to-Foot



SOT-23 (TO-236): 3-LEAD





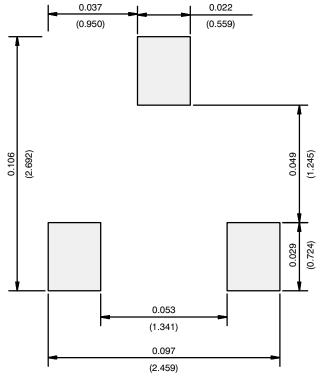


Dim -	MILLIMETERS		INCHES	
	Min	Max	Min	Max
Α	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
С	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
е	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.074	8 Ref
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025	Ref
S	0.50 Ref		0.020) Ref
q	3°	8°	3°	8°

DWG: 5479



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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